

Advanced Differential Sensor Signal Conditioner

Datasheet

Features

- Digital compensation of sensor offset, sensitivity, temperature drift and non-linearity
- Accommodates nearly all bridge sensor types (signal spans from 1 up to 275mV/V processable)
- Digital one-shot calibration: quick and precise
- Selectable compensation temperature T1 source: bridge, thermistor, internal diode or external diode
- Output options: voltage (0V to 5V), current (4mA to 20mA), PWM, I²C, SPI, ZACwireTM (one-wire-interface), alarm
- Adjustable output resolution (up to 15 bits) versus sampling rate (up to 3.9kHz)
- Selectable bridge excitation: ratiometric voltage, constant voltage or constant current
- Input channel for separate temperature sensor
- Sensor connection and common mode check (Sensor aging detection)
- Operation temperature -40 to +125°C (-40 to +150°C derated, depending on product version)
- Supply voltage +2.7V to +5.5V
- Available in SSOP16 or as die

Benefits

- No external trimming components required
- PC-controlled configuration and calibration via digital bus interface - simple, low cost
- High accuracy (±0.1% FSO @ -25°C to 85°C; ±0.25% FSO @ -40°C to 125°C)

Brief Description

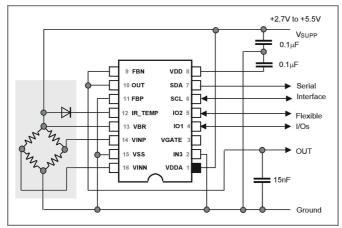
ZMD31050 is a CMOS integrated circuit for highlyaccurate amplification and sensor-specific correction of bridge sensor signals. The device provides digital compensation of sensor offset, sensitivity, temperature drift and non-linearity by a 16-bit RISC micro controller running a correction algorithm with correction coefficients stored in non-volatile EEPROM.

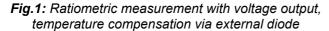
The ZMD31050 accommodates virtually any bridge sensor (e.g. piezo-resistive, ceramic-thick film or steel membrane based). In addition, the IC can interface a separate temperature sensor.

The bi-directional digital interfaces (I²C, SPI, ZACwireTM) can be used for a simple PC-controlled one-shot calibration procedure, in order to program a set of calibration coefficients into an on-chip EEPROM. Thus a specific sensor and a ZMD31050 are mated digitally: fast, precise and without the cost overhead associated with laser trimming, or mechanical potentiometer methods.

- Application kit available (SSOP16 samples, calibration PCB, calibration software, technical documentation)
- Support for industrial mass calibration available
- Quick circuit customization possible for large production volumes

Application Circuit (Examples)





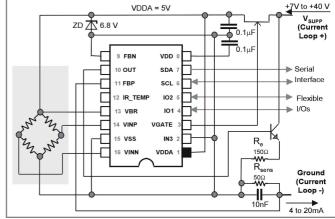


Fig.2: Two-wire-(4 to 20) mA configuration [(7 to 40) V], temperature compensation via internal diode

Refer also chapter 2 for additional application circuits and details.



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1. Circuit Description

1.1 Signal Flow

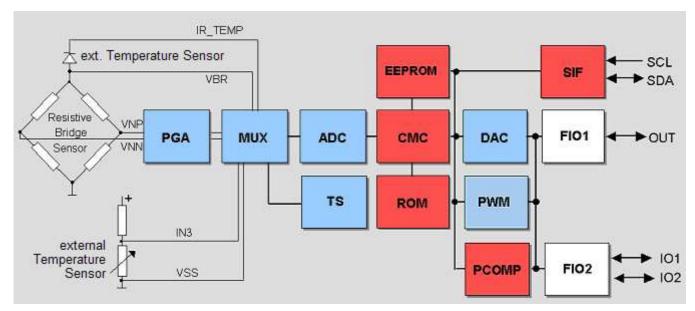


Fig.3: ZMD31050 Block Diagram

PGA	Programmable gain amplifier
MUX	Multiplexer
ADC	Analog-to-digital converter
CMC	Calibration microcontroller
DAC	Digital-to-analog converter
FIO1	Flexible I/O 1: analog out (voltage/current), PWM2,
	ZACwire [™] (one-wire-interface)
FIO2	Flexible I/O 2: PWM1, SPI data out, SPI slave select, Alarm1, Alarm2
SIF	Serial interface: I2C data I/O, SPI data in, clock
PCOMP	Programmable comparator
EEPROM	Non volatile memory for calibration parameters and configuration
TS	On-chip temperature sensor (pn-junction)
ROM	Memory for correction formula and –algorithm
PWM	PWM module

The ZMD31050's signal path is partly analog (blue) and partly digital (red). The analog part is realized differential – this means internal is the differential bridge sensor signal also handled via two signal lines, which are rejected symmetrically around a common mode potential (analog ground = VDDA/2). Consequently it is possible to amplify positive and negative input signals, which are located in the common mode range of the signal input.

The differential signal from the bridge sensor is pre-amplified by the programmable gain amplifier (PGA). The Multiplexer (MUX) transmits the signals from bridge sensor, external diode or separate



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temperature sensor to the ADC in a certain sequence (instead of the temperature diode the internal pnjunction (TS) can be used optionally). Afterwards the ADC converts these signals into digital values. The digital signal correction takes place in the calibration micro-controller (CMC). It is based on a special correction formula located in the ROM and on sensor-specific coefficients (stored into the EEPROM during calibration). Dependent on the programmed output configuration the corrected sensor signal is output as analog value, as PWM signal or in digital format (SPI, I²C, ZACwireTM). The output signal is provided at 2 flexible I/O modules (FIO) and at the serial interface (SIF). The configuration data and the correction parameters can be programmed into the EEPROM via the digital interfaces. The modular circuit concept enables fast custom designs varying these blocks and, as a result, functionality and die size.

1.2 Application Modes

For each application a configuration set has to be established (generally prior to calibration) by programming the on-chip EEPROM regarding to the following modes:

- Sensor channel
- Sensor mode: ratiometric voltage or current supply mode.
- Input range: The gain of the analog front end has to be chosen with respect to the maximum sensor signal span and to this has also adjusted the zero point of the ADC
- Additional offset compensation: The extended analog offset compensation has to be enabled if required, e.g. if the sensor offset voltage is near to or larger than the sensor span.
- Resolution/response time: The A/D converter has to be configured for resolution and converting scheme (first or second order). These settings influence the sampling rate, signal integration time and this way the noise immunity. The Sample Order influences the response time too.
- Ability to invert the sensor bridge inputs

Analog output

- Choice of output method (voltage value, current loop, PWM) for output register 1.
- Optional choice of additional output register 2: PWM via IO1 or alarm out module via IO1/2.
- **Digital communication**: The preferred protocol and its parameter have to be set.

Temperature

- The temperature measure source for the temperature correction has to be chosen.
- The temperature measure source T1 sensor type for the temperature correction has to be chosen (only T1 is usable for correction!!!)
- Optional: the temperature measure channel as the second output has to be chosen.
- Supply voltage: For non-ratiometric output the voltage regulation has to be configured.

Note: Not all possible combinations of settings are allowed (see section 1.5).

The calibration procedure must include

- Set of coefficients of calibration calculation
- and, depending on configuration,
 - Adjustment of the extended offset compensation,
 - Zero compensation of temperature measurement,
 - Adjustment of the bridge current
- and, if necessary,
 - Set of thresholds and delays for the alarms and the reference voltage.



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1.3 Analog Front End (AFE)

The analog front end consists of the programmable gain amplifier (PGA), the multiplexer (MUX) and the analog-to-digital converter (ADC).

1.3.1. Programmable Gain Amplifier

The following tables show the adjustable gains, the processable sensor signal spans and the allowed common mode range.

No.	PGA Gain a _{IN}	Gain Amp1	Gain Amp2	Gain Amp3	Max. span V _{IN_SP} in mV/V	Input range V _{IN_CM} in % VDDA *
1	420	30	7	2	2	43 - 57
2	280	30	4,66	2	3	40 - 59
3	210	15	7	2	4	43 - 57
4	140	15	4,66	2	6	40 - 59
5	105	15	3,5	2	8	38 - 62
6	70	7,5	4,66	2	12	40 - 59
7	52,5	7,5	3,5	2	16	38 - 62
8	35	3,75	4,66	2	24	40 - 59
9	26,3	3,75	3,5	2	32	38 - 62
10	14	1	7	2	50	43 - 57
11	9,3	1	4,66	2	80	40 - 59
12	7	1	3,5	2	100	38 - 62
13	2,8	1	1,4	2	280	21 - 76

Table 1: Adjustable gains, resulting sensor signal spans and common mode ranges

1.3.2. Extended Zero Point Compensation (XZC)

The ZMD31050 supports two methods of sensor offset cancellation (zero shift):

- Digital offset correction
- XZC an analog cancellation for large offset values (up to approx 300% of span)

The digital sensor offset correction will be processed at the digital signal correction/conditioning by the CMC. The analog sensor offset pre-compensation will be needed for compensation of large offset values, which would be overdrive the analog signal path by uncompensated gaining. For analog sensor offset pre-compensation a compensation voltage will be added in the analog pre-gaining signal path (coarse offset removal). The analog offset compensation in the AFE can be adjusted by 6 EEPROM bits. It allows an analog zero point shift up to 300% of the processable signal span.

The zero point shift of the temperature measurements can also be adjusted by 6 EEPROM bits $(Z_{XZC} = -20...+20)$ and is calculated by:

 $V_{XZC} / VDD_{BR} = k * Z_{XZC} / (20 * a_{IN})$

^{*} Bridge in voltage mode, refer "ZMD31050 Functional description" for usable input signal/common mode range at bridge in current mode



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PGA gain a _{IN}	Max. span V _{IN_SP} in mV/V	Calculation factor k	Offset shift per step in % full span	Approx. maximum offset shift in mV/V	Approx. maximum shift in [% V _{IN_SP}] (@ ± 20 steps)
420	2	3,0	15%	+/- 7	330
280	3	1,833	9%	+/- 6	200
210	4	3,0	15%	+/- 14	330
140	6	1,833	9%	+/- 12	200
105	8	1,25	6%	+/- 12	140
70	12	1,833	9%	+/- 24	200
52,5	16	1,25	6%	+/- 22	140
35	24	1,833	9%	+/-48	200
26,3	32	1,25	6%	+/- 45	140
14	50	3,0	15%	+/- 180	330
9,3	80	1,833	9%	+/- 160	200
7	100	1,25	6%	+/- 140	140
2,8	280	0,2	1%	+/- 60	22

Table 2: Extended Zero Point Compensation Range

Note: Z_{xzc} can be adjusted in range -31 to 31, parameters are guaranteed only in range -20 to 20.

1.3.3. Measurement Cycle realized by Multiplexer

The Multiplexer selects, depending on EEPROM settings, the following inputs in a certain sequence.

- Internal offset of the input channel measured by input short circuiting
- Bridge temperature signal measured by external and internal diode (pn-junction)
- Bridge temperature signal measured by bridge resistors
- Separate temperature signal measured by external thermistor
- The complete measurement cycle is controlled by the CMC. The cycle diagram

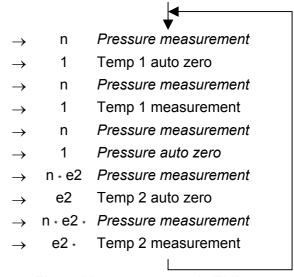
Pre-amplified bridge sensor signal

The EEPROM adjustable parameters are:

at the right shows its principle structure.

- Pressure measurement count, n=<1,2,4,8,16,32,64,128>
- Enable temperature measurement 2, e2=<0,1>

After Power ON the start routine is called. It contains the pressure and auto zero measurement. When enabled it measures the temperature and its auto zeros.



Start routine

Fig. 4: Measurement cycle ZMD31050



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1.3.4. Analog-to-Digital Converter

The ADC is a charge balancing converter in full differential switched capacitor technique. It can be used as first or second order converter:

In the **first order** mode it is inherently monotone and insensitive against short and long term instability of the clock frequency. The conversion cycle time depends on the desired resolution and can be roughly calculated by:

$$t_{CYC_1} = 2^{r_{ADC}} \mu s$$

The available ADC-resolutions are $r_{ADC} = <9,10,11,12,13,14>$.

In the **second order** mode two conversions are stacked with the advantage of much shorter conversion cycle time and the drawback of a lower noise immunity caused by the shorter signal integration period. The conversion cycle time at this mode is roughly calculated by:

$$t_{CYC_2} = 2^{(r_{ADC} + 3)/2} \mu s$$

The available ADC-resolutions are $r_{ADC} = <11,12,13,14,15>$.

The result of the AD conversion is a relative counter result corresponding to the following equation:

$$Z_{ADC} = 2^{r_{ADC}} * [(V_{ADC_DIFF}/V_{ADC_REF}) + (1 - RS_{ADC})]$$

 $\begin{array}{ll} Z_{ADC} \colon & \text{Number of counts (result of the conversion)} \\ V_{ADC_DIFF} \colon & \text{Differential input voltage of ADC (= a_{IN} * V_{IN_DIFF})} \\ V_{ADC_REF} \colon & \text{Reference voltage of ADC (= VBR or VDDA)} \\ \end{array}$

RS_{ADC}: Digital ADC Range Shift (RS_{ADC} = $^{15}/_{16}$, $^{7}/_{8}$, $^{3}/_{4}$, $^{1}/_{2}$, controlled by the EEPROM content)

With the RS_{ADC} value a sensor input signal can be shifted in the optimal input range of the ADC.

The Pin <VBR>-potential is used in "VBR=VREF" mode as AD converters reference voltage V_{ADC_REF} . Sensor bridges with no ratiometric behaviour (f.i. temperature compensated bridges), which are supplied by a constant current, requires VDDA potential as V_{ADC_REF} and this can be adjusted by in configuration. If these mode is enabled, XZC can't by used (adjustment=0), but it has to be enabled (refer calculation sheet "ZMD31050_Bridge_Current_Excitation_Rev*.xls" for details).

Note: The AD conversion time (sample rate) is only a part of a whole signal conditioning cycle.

ADC		Maximum Out	Sample Rate f _{CON}			
Order	r _{ADC} 1	Digital-OUT	Analog-OUT r _{PWM}		f _{CLK} =2MHz	f _{CLK} =2.25MHz
O _{ADC}	Bit	Bit	Bit	Bit	Hz	Hz
1	9	9	9	9	1302	1465
1	10	10	10	10	781	879
1	11	11	11	11	434	488
1	12	12	11	12	230	259
1	13	13	11	12	115	129
1	14	14	11	12	59	67

¹ ADC Resolution should be 1 to 2 Bits higher then applied Output Resolution



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ADC		Maximum Out	Sample Rate f _{CON}			
Order	r _{ADC} 1	Digital-OUT Analog-OUT r _{PWM}		f _{CLK} =2MHz	f _{CLK} =2.25MHz	
O _{ADC}	Bit	Bit	Bit	Bit	Hz	Hz
2	10	10	10	10	3906	4395
2	11	11	11	11	3906	4395
2	12	12	11	12	3906	4395
2	13	13	11	12	1953	2197
2	14	14	11	12	1953	2197
2	15	15	11	12	977	1099

Table 3: Output Resolution versus Sample Rate

1.4 System Control

The system control has the following features:

- Control of the I/O relations and of the measurement cycle regarding to the EEPROM-stored configuration data
- 16 bit correction calculation for each measurement signal using the EEPROM stored calibration coefficients and ROM-based algorithms
- Started by internal POC, internal clock generator or external clock
- For safety improvement the EEPROM data are proved with a signature within initialization procedure, the registers of the CMC are steadily observed with a parity check. Once an error is detected, the error flag of the CMC is set and the outputs are driven to a diagnostic value

Note: The conditioning includes up to third order sensor input correction. The available adjustment ranges depend on the specific calibration parameters, a detailed description will be issued later. To give a rough idea: Offset compensation and linear correction are only limited by the loose of resolution it will cause, the second order correction is possible up to about 20% full scale difference to straight line, third order up to about 10% (ADC resolution = 13bit). The temperature calibration includes first and second order correction and should be fairly sufficient in all relevant cases. ADC resolution influences also calibration possibilities — 1 bit more resolution reduces calibration range by approximately 50%.

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¹ ADC Resolution should be 1 to 2 Bits higher then applied Output Resolution



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1.5 Output Stage

	Used	I SIF	Used I/O pins						
No.	I ² C	SPI	OUT	IO1	IO2	SDA			
1	Х					Data I/O			
2	Х			ALARM1		Data I/O			
3	Х				ALARM2	Data I/O			
4	Х			ALARM1	ALARM2	Data I/O			
5	Х			PWM1		Data I/O			
6	Х			PWM1	ALARM2	Data I/O			
7	Х		Analog			Data I/O			
8	Х		Analog	ALARM1		Data I/O			
9	Х		Analog		ALARM2	Data I/O			
10	Х		Analog	ALARM1	ALARM2	Data I/O			
11	Х		Analog	PWM1		Data I/O			
12	Х		Analog	PWM1	ALARM2	Data I/O			
13	Х		PWM2			Data I/O			
14	Х		PWM2	ALARM1		Data I/O			
15	Х		PWM2		ALARM2	Data I/O			
16	Х		PWM2	ALARM1	ALARM2	Data I/O			
17	Х		PWM2	PWM1		Data I/O			
18	Х		PWM2	PWM1	ALARM2	Data I/O			
19		Х		Data out	Slave select	Data in			
20		х		Data out ALARM1	Slave select -	Data in -			
21		x		Data out PWM1	Slave select -	Data in			
22		Х	Analog	Data out	Slave select	Data in			
23		х	Analog	Data out ALARM1	Slave select -	Data in -			
24		х	Analog	Data out PWM1	Slave select -	Data in -			
25		Х	PWM2	Data out	Slave select	Data in			
26		X	PWM2	Data out ALARM1	Slave select -	Data in			
27	Y7 X		PWM2	Data out PWM1	Slave select -	Data in			

Table 4: Output configurations overview

The ZMD31050 provides the following I/O pins: OUT, IO1, IO2 and SDA.

Via these pins the following signal formats can be output: Analog (voltage/current), PWM, Data (SPI/I²C), Alarm.

The following values can be provided at the O/I pins: bridge sensor signal, temperature signal 1, temperature signal 2, alarm.

Note:

The Alarm signal only refers to the bridge sensor signal, but never to a temperature signal.

Due to the necessary pin sharing there are restrictions to the possible combinations of outputs and interface connections.

The table beside gives an overview about possible combinations.

Note:

In the SPI mode the pin IO2 is used as Slave select. Thus no Alarm 2 can be output in this mode.



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1.5.1. Analog Output

For the analog output 3 registers of 15 bit depth are available, which can store the actual pressure and the results of temperature measurement 1 and 2. Each register can be independently switched to one of two output slots connected to the Pin OUT and IO1 respectively. In these output slots different output modules are available according to the following table:

Output slot:	OUT	IO1
Voltage	Х	
PWM	Х	Х

Table 5: Analog output configuration

The voltage module consists of an 11bit resistor string – DAC with buffered output and a subsequent inverting amplifier with class AB rail-to-rail OpAmp. The two feedback nets are connected to the Pins FBN and FBP. This structure offers wide flexibility for the output configuration, for example voltage output and 4 mA to 20 mA current loop output. To short circuit the analog output against VSS or VDDA does not damage the ZMD31050.

The PWM module provides pulse streams with signal dependent duty cycle. The PWM – frequency depends on resolution and clock divider. The maximum resolution is 12 bit, the maximum PWM – frequency is 4 kHz (9 bit). If both, second PWM and SPI protocol are activated, the output pin IO1 is shared between the PWM output and the SPI_SDO output of the serial interface (interface communication interrupts the PWM output).

1.5.2. Comparator Module (ALARM Output)

The comparator module consists of two comparator channels connectable to IO1 and IO2 respectively. Each of them can be independently programmed referring to the parameters threshold, hysteresis, switching direction and on/off – delay. Additional a window comparator mode is available.

1.5.3. Serial Digital Interface

The ZMD31050 includes a serial digital interface which is able to communicate in three different communication protocols – I^2C^{TM} , SPI^{TM} and $ZACwire^{TM}$ (one wire communication). In the SPI mode the pin IO2 operates as slave select input, the pin IO1 as data output.

Initializing Communication

After power-on the interface is for about 20ms (start window) in the state ZACwire. During the start window it is possible to communicate via the one wire interface (pin OUT).

Detecting a proper request inside the start window the interface stays in the state ZACwire. This state can be left by certain commands or a new power-on.

If during the start window no request happens then the serial interface switches to I²C or SPI mode (depending on EEPROM settings). The OUT pin is used as analog output or as PWM output (also depending on EEPROM settings). The start window can generally be disabled (or enabled) by a special EEPROM setting.

For detailed description of the serial interfaces see "ZMD31050 Functional Description".



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1.6 Voltage Regulator

For ratiometric applications 3V to 5V ($\pm 10\%$) the external supply voltage can be used for sensor element biasing. If an absolute analog output is desired then the internal voltage regulator with external power regulation element (JFET) can be used. The regulation is bandgap reference based and designed for an external supply voltage V_{SUPP} in the range of 7V to 40VDC. The internal supply and sensor bridge voltage can be varied between 3V and 5.5V in 4 steps with the voltage regulator.

1.7 Watchdog and Error Detection

The ZMD31050 detects various possible errors. A detected error is signalized by changing in a diagnostic mode. In this case the analog output is set to the high or low level (maximum or minimum possible output value) and the output registers of the digital serial interface are set to a significant error code.

A watchdog oversees the continuous working of the CMC and the running measurement loop.

A check of the sensor bridge for broken wires is done permanently by two comparators watching the input voltage of each input [(VSSA + 0.5V)] to (VDDA - 0.5V). Add on the common mode voltage of the sensor is watched permanently (sensor aging).

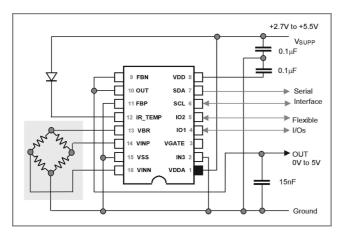
Different functions and blocks in digital part are watched like RAM-, ROM,- EEPROM- and Register content continuously, the document "ZMD31050 Functional Description" contains in chapter 1.3.4 a detailed description of all watched blocks and methods of messaging of errors.

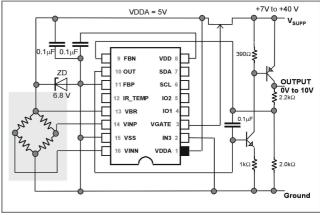


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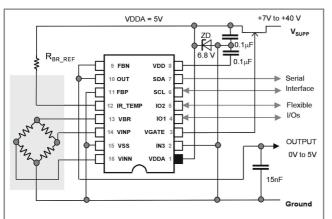
2. **Application Circuit Examples**



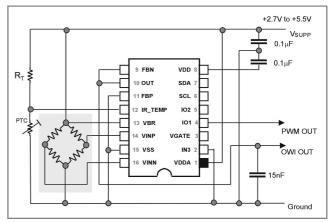


Example 1

Typical ratiometric measurement with voltage 0V to 10V output configuration, supply regulator output, temperature compensation via external (external JFET), temperature compensation via diode, internal VDD regulator and active sensor internal diode and bridge in voltage mode connection check (bridge must not be at VDDA)



Example 2



Example 3

Absolute voltage supply regulator Ratiometric output, (external JFET), constant current excitation of measurement, 3-wire connection for end of line the sensor bridge, temperature compensation by calibration at pin OUT (ZACwire™), additional bridge voltage drop measurement, internal VDD temperature regulator without ext. capacitor

Example 4

bridge differential signal measurement with external thermistor and PWM-output at pin IO1

Hints: It is possible to combine or split connectivity of different application examples. For VDD generation ZMD recommends to use internal supply voltage regulator with external capacitor. Notice additional application notes for usage of supply voltage regulation property (non ratiometric mode) and current loop output mode.



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3. ESD/Latch-Up-Protection

All pins have an ESD protection of >2000V (except the pins INN, INP and FBP with > 1200V) and a latch-up protection of ± 100 mA or of ± 8 V/ ± 4 V (to VSS/VSSA) – refer chapter 4 for details and restrictions. ESD protection referred to the human body model is tested with devices in SSOP16 packages during product qualification. The ESD test follows the human body model with 1.5kOhm/100pF based on MIL 883, method 3015.7.

4. Pin Configuration and Package

Pin	Name	Description	Remarks	Latch-Up related Application Circuit Restrictions and/or Remarks
1	VDDA	Positive analog supply voltage	Supply	
2	IN3	Resistive temp sensor IN & external clock IN	Analog IN	Free accessible (latch-up related)
3	VGATE	Gate voltage for external regulator FET	Analog OUT	Only connection to external FET
4	IO1	SPI data out & ALARM1 & PWM1 Output	Digital IO	Free accessibility
5	IO2	SPI chip select & ALARM2	Digital IO	Free accessibility
6	SCL	I ² C clock & SPI clock	Digital IN, pull-up	Free accessibility
7	SDA	Data IO for I ² C & data IN for SPI	Digital IO, pull-up	Free accessibility
8	VDD	Positive digital supply voltage	Supply	Only short to VDDA or capacitor to VSS allowed, otherwise no application access
9	FBN	Negative feedback connection output stage	Analog IO	Free accessibility
10	OUT	Analog output & PWM2 Output & one wire interface i/o	Analog OUT & dig. IO	Free accessibility
11	FBP	Positive feedback connection output stage	Analog IO	Free accessibility
12	IR_TEMP	Current source resistor i/o & temp. diode in	Analog IO	Circuitry secures potential inside of VSS-VDDA range, otherwise no application access
13	VBR	Bridge top sensing in bridge current out	Analog IO	Only short to VDDA or connection to sensor bridge, otherwise no application access
14	VINP	Positive input sensor bridge	Analog IN	Free accessibility
15	VSS	Negative supply voltage	Ground	
16	VINN	Negative input sensor bridge	Analog IN	Free accessibility

Table 6: Pin Configuration

The standard package of the ZMD31050 is a SSOP16 (5.3mm body width) with lead-pitch 0.65mm:

Pin-Nr 9 10 11 12 13 14	Pin-Name FBN OUT FBP IR_TEMP VBR VINP	ZMD U23456 abcd xxxx YYWW	Pin-Name VDD SDA SCL IO2 IO1 VGATE	Pin-Nr 8 7 6 5 4 3
14	VINP		VGATE	3
15	VSS		IN3	2
16	VINN		VDDA	1



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5. **IC Characteristics**

5.1 **Absolute Maximum Ratings**

No.	Parameter	Symbol	min	typ	max	Unit	Conditions
5.1.1	Digital Supply Voltage	VDD _{AMR}	-0.3		6.5	V DC	To VSS
5.1.2	Analog Supply Voltage	VDDA _{AMR}	-0.3		6.5	V DC	To VSS
5.1.3	Voltage at all analog and digital I/O – Pins	V _{A_I/O} , V _{D_I/O}	-0.3		VDDA +0.3	V DC	Exception see 5.1.4
5.1.4	Voltage at Pin FBP	V _{FBP_AMR}	-1.2		VDDA +0.3	V DC	4 mA to 20mA – Interface
5.1.5	Storage temperature	T _{STG}	-45		150	°C	

Operating Conditions ¹ 5.2

(Voltages related to VSS)

No.	Parameter	Symbol	min	typ	max	Unit	Conditions
5.2.1	Ambient temperature advanced performance	T _{ADV}	-25		85	°C	TQI = -25 to 85°C TQC = 0 to 70°C
5.2.2.1	Ambient temperature Automotive range	T _{AMB_TQA}	-40		125	°C	
5.2.2.2	Ambient temperature Extended automotive range	T _{AMB_TQE}	-40		150	°C	Operation life time < 1000h @ 125 to 150°C
5.2.3	Ambient temperature EEPROM programming	T _{AMB_EEP}	-25		85	°C	
5.2.4	EEPROM programming cycles				100		
5.2.5	Data retention (EEPROM)				15	а	Averaged temp < 85°C
5.2.6	Analog Supply Voltage	VDDA	2.7		5.5	V DC	Ratiometric mode
5.2.7	Analog Supply Voltage advanced performance	VDDA _{ADV}	4.5		5.5	V DC	Ratiometric mode
5.2.8	Digital Supply Voltage	VDD	- 2.7		1.05 -	VDDA V DC	External powered
5.2.9	External Supply Voltage	V_{SUPP}	VDDA + 2V		2	V DC	Voltage regulator mode with ext. JFET

¹ Default configuration: 2nd order AD-conversion, 13Bit Resolution, gain >=210, fclk<=2.25MHz ² Maximum depending on breakdown voltage of external JFET, notice application hints in related application note.



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No.	Parameter	Symbol	min	typ	max	Unit	Conditions
5.2.10	Common mode input range	V _{IN_CM}	0.21		0.76	V _{ADC_REF}	Depends on gain adjustment - refer chapter 1.3.1
5.2.11	Input Voltage Pin FBP	V _{IN_FBP}	-1		VDDA	V DC	
5.2.12	Sensor Bridge Resistance *	R _{BR}	3.0 ¹ 5.0		25.0 25.0	kΩ kΩ	Full temperature range 4mA to 20mA – Interface
5.2.13	Reference Resistor for Bridge Current Source *	R _{BR_REF}	0.07			R _{BR}	Leads to $I_{BR} = V_{DDA} / (16.R_{BR_REF})$
5.2.14	Stabilization Capacitor *	C_{VDDA}	50	100	470	nF	Between VDDA and VSS, external
5.2.15	VDD Stabilization Capacitor *	C_{VDD}	0 2	100	470	nF	Between VDD and VSS, external
5.2.16	Maximum allowed load capacitance at OUT ³	C _{L_OUT}			50	nF	Output Voltage mode
5.2.17	Minimum allowed load resistance	R _{L_OUT}	2			kΩ	Output Voltage mode
5.2.18	Maximum allowed load capacitance at VGATE	C _{L_VGATE}			10	nF	Summarized to all potentials

5.3 **Build In Characteristics**

No.	Parameter	Symbol	min	typ	max	Unit	Conditions
5.3.1	Selectable Input Span, Pressure Measurement	V_{IN_SP}	2		280	mV/V	Refer chapter 1.3.1
5.3.2	Analog Offset Comp Range (6 Bit setting)		-20 -25		20 25	count	ADJREF:BCUR=7
5.3.3	A/D Resolution	r _{ADC}	9		15	Bit	3 Bit setting 4
5.3.4	D/A Resolution	r _{DAC}		11		Bit	@ analogue output
5.3.5	PWM - Resolution	r _{PWM}	9		12	Bit	
5.3.6	Bias current for external temperature diodes	I _{TS}	8	18	40	μΑ	
5.3.7	Sensitivity internal temperature diode	ST _{T_SI}	2800	3200	3600	ppm f.s. /K	Raw values - without conditioning

^{*} No measurement in mass production, parameter is guarantied by design and/or quality observation

No limitations with an external connection between VDDA and VBR

1 No limitations with an external connection between VDDA and VBR

2 Lower stabilization capacitors can increase noise level at the output

3 If used, consider special requirements of ZACwire™ single wire interface stated in "Functional Description" chapter 4.3

4 Resolution of 15bit is not applicable for 1st order ADC and not recommended for sensors with high nonlinearity behaviour



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5.3.8 Cycle Rate versus A/D-Resolution *

(linear related to master clock frequency¹ - values calculated at exact 2 MHz)

ADC Order	Resolution	Conversion Cycle f _{CYC}					
O _{ADC}	r _{ADC}	f _{CLK} =2MHz	f _{CLK} =2.25MHz				
	Bit	Hz	Hz				
1	9	1302	1465				
	10	781	879				
	11	434	488				
	12	230	259				
	13	115	129				
	14	59	67				
2	11	3906	4395				
	12	3906	4395				
	13	1953	2197				
	14	1953	2197				
	15	977	1099				

5.3.9 PWM Frequency *

PWM	PWM F	req./Hz a	at 2 MHz	Clock ¹	PWM Freq./Hz at 2.25 MHz Clock ²				
Resolution		Clock I	Divider		Clock Divider				
r _{PWM} [Bit]	1 0,5 0,25 0,125		1	0,5	0,25	0,125			
9	3906	1953	977	488	4395	2197	1099	549	
10	1953	977	488	244	2197	1099	549	275	
11	977	488	244	122	1099	549	275	137	
12	488	244	122	61	549	275	137	69	

^{*} No measurement in mass production, parameter is guarantied by design and/or quality observation

¹ Internal RC – Oscillator: coarse adjustment to1, 2 and 4 MHz, fine tuning +/- 25%, external clock is also possible ² Internal RC – Oscillator: coarse adjustment to1.125, 2.25 and 4.5 MHz, fine tuning +/- 25%, external clock is also possible



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5.4 Electrical Parameters

(Voltages related to VSS)

No.	Parameter	Symbol	min	typ	max	Unit	Conditions			
5.4.1 Supply / Regulation										
5.4.1.1	Supply current	I _{SUPP}		2.5	4	mA	Without bridge and load current, fclk≤2.4MHz, Bias-Adjust≤4			
5.4.1.2	Supply current for current loop	I _{SUPP_CL}		2.0	2.75		Without bridge current, fcLK≤1.2MHz, Bias-Adjust≤1 ¹			
5.4.1.2	Temperature Coeff. Voltage Reference *	TC _{REF}	-200	±50	200	ppm/K				
		5.4.2	Analog	Fron	t End					
5.4.2.1	Parasitic differential input offset current *	I _{IN_OFF}	-2 to -10		2 to 10	nA	Temp. range 5.2.2., T _{ADV}			
	5.4	1.3 DAC &	Analog	Outp	ut (Pin	OUT)				
5.4.3.1	Output signal range	$V_{\text{OUT_SR}}$	0.025		0.975	VDDA	Voltage Mode, assuming minimum load of 2k VDDA _{ADV} ,T _{ADV} ²			
5.4.3.2	Output DNL	DNL_OUT			0.95	LSB	VDDA _{ADV} ,T _{ADV}			
5.4.3.3	Output INL	INL _{OUT}			4	LSB	3			
5.4.3.4	Output slew rate *	SR _{OUT}	0.1			V/μs	Voltage mode, C _L <20nF, using conditions of 5.4.3.1			
5.4.3.5	Short circuit current *	I _{OUT_max}	5	10	20	mA				
5.4.3.6	Addressable output signal range *	$V_{\text{OUT_ADR}}$	0		1	VDDA	2048 steps			
		5.4.4 PWI	/ Output	t (Pin	OUT, I	01)				
5.4.4.1	PWM high voltage	V_{PWM_H}	0.9			VDDA	$R_L > 10 \text{ k}\Omega$			
5.4.4.2	PWM low voltage	V_{PWM_L}			0.1	VDDA	$R_L > 10 \text{ k}\Omega$			
5.4.4.3	PWM output slew rate*	SR _{PWM}	15			V/μs	C _L < 1nF			
	5.4.5	Tempera	ture Ser	sors	(Pin IR	_TEMP)				
5.4.5.1	Sensitivity external diode / resistor meas.	ST _{TS_E}	75		210	μV/LSB	At r _{ADC} = 13 Bit			
	5.4.6 Digital Outputs (IO1, IO2, OUT in digital mode)									
5.4.6.1	Output-High-Level	V_{DOUT_H}	0.9			VDDA	$R_L > 1 k\Omega$			
5.4.6.2	Output-Low-Level	V_{DOUT_L}			0.1	VDDA	$R_L > 1 k\Omega$			
5.4.6.3	Output Current *	I _{DOUT}	4			mA				

¹ Recommended bias adjust <= 4, notice application hints and power consumption adjust constraints in related application note

² Derated performance in lower part of supply voltage range (2.7 to 3.3V): 2.5 to 5%VDDA & 95 to 97.5%VDDA

Output linearity and accuracy can be enhanced by additional analog output stage calibration

^{*} No measurement in mass production, parameter is guarantied by design and/or quality observation



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No.	Parameter	Symbol	min	typ	max	Unit	Conditions			
5.4.7 System Response										
5.4.7.1	Startup time ¹ ,*	t _{STA}	2		5	ms	PowerOn to first measure result at output			
5.4.7.2	Response time *	t_{RESP}	1.66	2.66	3.66	1/f _{CON}	66% jump, refer 1.3.4 for f _{CON}			
5.4.7.3	Overall accuracy (deviation	AC _{OUT}			0.1	%	T _{ADV} , VDDA _{ADV}			
	from ideal line including INL gain and offset errors) 2,*	,			0.25	%	T _{AMB} & T _{ADV} ,VDDA _{ADV} @ ADJREF:BCUR<4			
5.4.7.4	Analog Output Noise	$V_{\text{NOISE,PP}}$			10	mV	Shorted inputs, gain<=210			
	Peak-to-Peak *						bandwidth ≤ 10kHz			
5.4.7.5	Analog Output Noise	$V_{\text{NOISE},\text{RMS}}$			3	mV	Shorted inputs, gain<=210			
	RMS *						bandwidth ≤ 10kHz			
5.4.7.6	Ratiometricity Error	RE _{OUT_5V}			500	ppm	±5% respect. 1000ppm ±10% (5V)			
		RE _{OUT_3V}			1000	ppm	±5% respect. 2000ppm ±10% (3V)			

5.5 **Interface Characteristics**

No.	Parameter	Symbol	min	typ	max	Unit	Conditions			
5.5.1 Multiport Serial Interfaces (I ² C, SPI)										
5.5.1.1	Input-High-Level	$V_{I2C_IN_H}$	0.7		1	VDDA				
5.5.1.2	Input-Low-Level	$V_{I2C_IN_L}$	0		0.3	VDDA				
5.5.1.3	Output-Low-Level	V _{I2C_OUT_L}			0.1	VDDA				
5.5.1.4	Load capacitance @ SDA	C _{SDA}			400	pF				
5.5.1.5	Clock frequency SCL 3	f _{SCL}			400	kHz	f _{CLK} ≥ 2MHz			
5.5.1.6	Pull-up Resistor	R _{I2C_PU}	500			Ω				
	5.5.2 Oı	ne Wire Sei	rial Int	terfac	e (ZAC	wire™)				
5.5.2.1	OWI start window	R _{OWI_PU}		20		ms				
5.5.2.2	Pull-up resistance master	R _{OWI_PU}	330			Ω				
5.5.2.3	OWI load capacitance	C_{OWI_LOAD}			0.08	t _{OWI_BIT} / R _{OWI_PU}	20μs < t _{OWI_BIT} < 100μs			
5.5.2.4	Voltage level Low	V_{OWI_L}			0.2	VDDA				
5.5.2.5	Voltage level High	V _{OWI_H}	0.75			VDDA				

^{*} No measurement in mass production, parameter is guarantied by design and/or quality observation

¹ OWI – start window disabled, according default configuration

⁽depends on resolution and configuration - start routine begins approximately 0.8ms after power on)

Accuracy better than 0.5% requires offset and gain calibration for the analog output stage

Internal clock frequency f_{CLK} has to be in minimum 5 times higher than communication clock frequency



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6. Reliability

A reliability investigation according to the in-house non-automotive standard will be performed.

7. Customization

For high-volume applications, which require an up- or downgraded functionality compared to the ZM31050, ZMD can customize the circuit design by adding or removing certain functional blocks. For it ZMD has a considerable library of sensor-dedicated circuitry blocks.

Thus ZMD can provide a custom solution quickly. Please contact ZMD for further information.

8. Related Documents

- ZMD31050 Feature Sheet
- ZMD31050 Functional Description
- ZMD31050 Evaluation Kit Description
- ZMD31050 Development Status Report (including parts identification table)
- ZMD31050 Application Notes

For the most recent revisions of this document and of the related documents, please go to www.zmd.biz

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